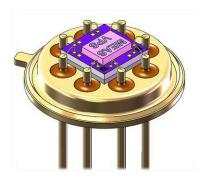


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### **Features**

- Measuring range of atmosphere to 10<sup>-4</sup> mbar
- Silicon Micromachining Technology
- TO-5 Housing
- Small Time Constant
- For use in reactive gas atmosphere there is a version with protective coating available

# **Applications**

- Pirani Gauges
- Industrial Application
- Gas Analysis Mass Spectrometry
- Vacuum Pumping Systems

# VPS025A VPS025P

Vacuum Pressure Sensor

# **Product Description**

The sensor element consists of a silicon chip with a thin membrane approximately  $1\text{mm}^2$  in size of a material with extremely good electrical and thermal insulating properties. On the membrane are two thin film resistors  $(R_{m1},\,R_{m2})$  which are both used for heating the membrane and for measurement of membrane temperature  $T_m$ . The resistors are passivated to protect them from the effects of the gas. The membrane is completely covered by a second small silicon chip with a rectangular cavity etched in. The hollow space thus formed above the membrane is the thermal conductivity section. The gas comes to the measuring section through a small lateral opening in the membrane cover by diffusion only, and not by flow.

The sensor chip and its cover are attached to a silicon support which also permits gas exchange to the lower side of the membrane. The sensor is electrically connected to an eight-pin base by gold wire bonding.

Due to the residual gas surrounding the membrane, thermal energy is dissipated from the membrane held at higher temperature  $T_{\text{m}}.$  Measured is the signal needed in a temperature stabilization circuit to keep the excess temperature of the membrane  $\Delta T$  constant.

On the solid part of the chip are two more resistors ( $R_{t1}$ ,  $R_{t2}$ ) to measure and compensate for the effect of the ambient temperature  $\vartheta$ .

The die stack is mounted on top of a TO-39 header with welding projection flange to be welded directly inside a third-party housing.

For use in reactive gas atmosphere there is the version of VPS025P. The whole silicon stack is covered with a thin film of special coating to make it robust against silicon etching gases.

# **Specifications**

### **Absolute Maximum Ratings**

#### **Recommended Operating Conditions**

 $\begin{array}{lll} \mbox{Heating power} & P \; (R_{m1} + R_{m2}) & 5 \; \mbox{mW} \\ \mbox{Membrane excess} & \Delta T = T_M - \vartheta & +50 \; ^{\circ} \mbox{C} \\ \mbox{temperature} & \end{array}$ 

The minimum  $\Delta T$  for any application is determined by the resolution of thermal conductivity  $\lambda$  required in combination with the noise of the amplifier circuit used. A very low  $\Delta T$  has advantages in terms of linearity, low drift and better long-term stability of the sensor.

#### **Parameter Specifications**

**Base Material** 

Resistances Heater	$R_{m1};R_{m2}$	100 +15/-8 Ω	at +25 °C
Resistances Difference Heaters	$R_{m1}$ - $R_{m2}$	+2.00 Ω	at +25 °C
Resistances Ambient Temperature Sensor	R <sub>t1</sub> ; R <sub>t2</sub>	240 +35/-20 Ω	at +25 °C
Resistance Ration	$R_{tx/}(R_{m1} + R_{m2})$	1.20 ± 0.07	$x \in \{1; 2\}$
Temperature Coefficient of Resistance $R_{tx}$ ; $R_{mx}$	α	5500 +400/-700 ppm/K	at 20 °C ↔ 100 °C
Geometry Factor	G	3.6 mm The factor G is deter	rmined by the internal sensor geometry.
Membrane thermal time constant	$\tau_{M}$	<5 ms	
Membrane thermal time constant Protective Coating Thickness	τ <sub>M</sub>	<5 ms 1.20 ± 0.12 μm	for G-VPSCO-004 "VPS025P" only
	$ au_{M}$		for G-VPSCO-004 "VPS025P" only pins from bottom of sensor base downwards; for G-VPSCO-004 "VPS025P" only
Protective Coating Thickness	τ <sub>M</sub> gvps025A	1.20 ± 0.12 μm	pins from bottom of sensor base downwards;
Protective Coating Thickness  Non Coated Area		1.20 ± 0.12 μm 1.8 mm	pins from bottom of sensor base downwards; for G-VPSCO-004 "VPS025P" only
Protective Coating Thickness  Non Coated Area  Distance between membrane and	gvps025A	1.20 ± 0.12 μm 1.8 mm 24.0 ± 2.0 μm	pins from bottom of sensor base downwards; for G-VPSCO-004 "VPS025P" only for G-VPSCO-005 "VPS025A" for G-VPSCO-004 "VPS025P"

Base material for the dies is silicon.

# **Electrical Connections**

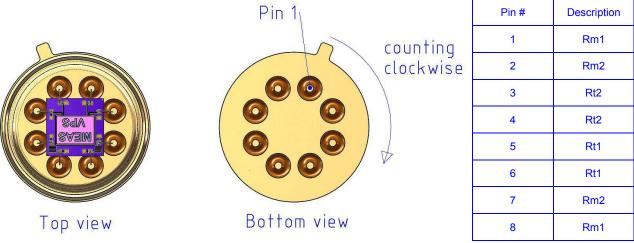


Figure 1: Pin assignment of electrical connections to top and bottom view of sensor

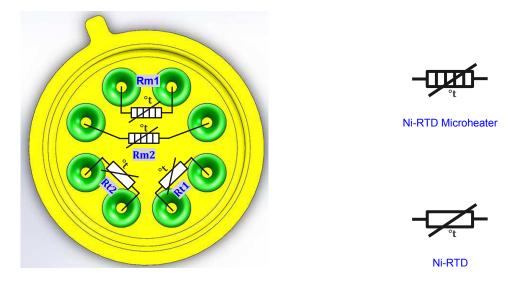


Figure 2: Equivalent Circuit Diagramm

# **Mechanical Dimensions**

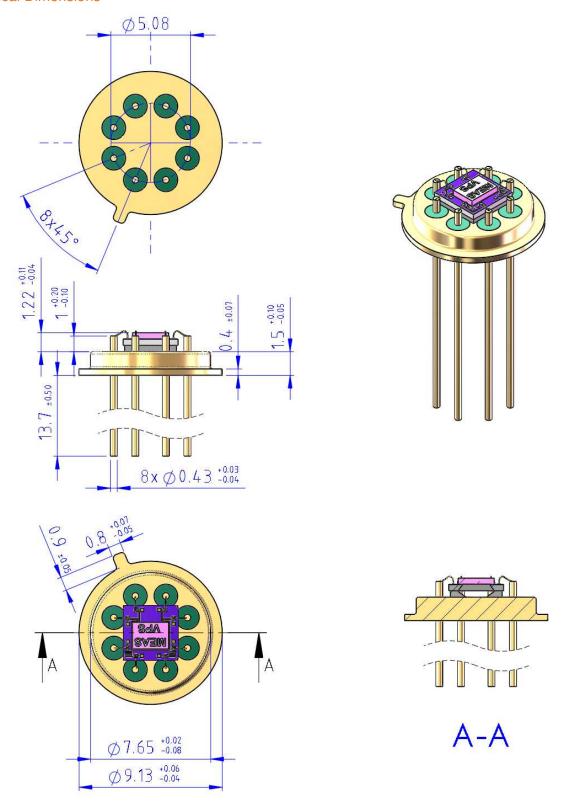


Figure 3: Mechanical dimensions of sensor – all dimensions in mm

# Ordering Information

Description	Part Number
VPS025A	G-VPSCO-005
VPS025P	G-VPSCO-004

VPS025A is the standard version.

VPS025P is the version with protective coating.

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